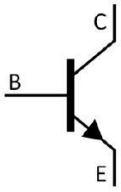
WR0<5+U, ṂṂÞ QSQ ÆṀ ч s ‖ ㄱ Silicon NPN transistor in a TO-92(R) Plastic Package.

ㅊ Ɔ я /ль EF889 Йį ´
High voltage, complementary to BC556.

₹ ˘ ѽ ᶻ ȝ Ầ ԋ
General purpose and switching application.

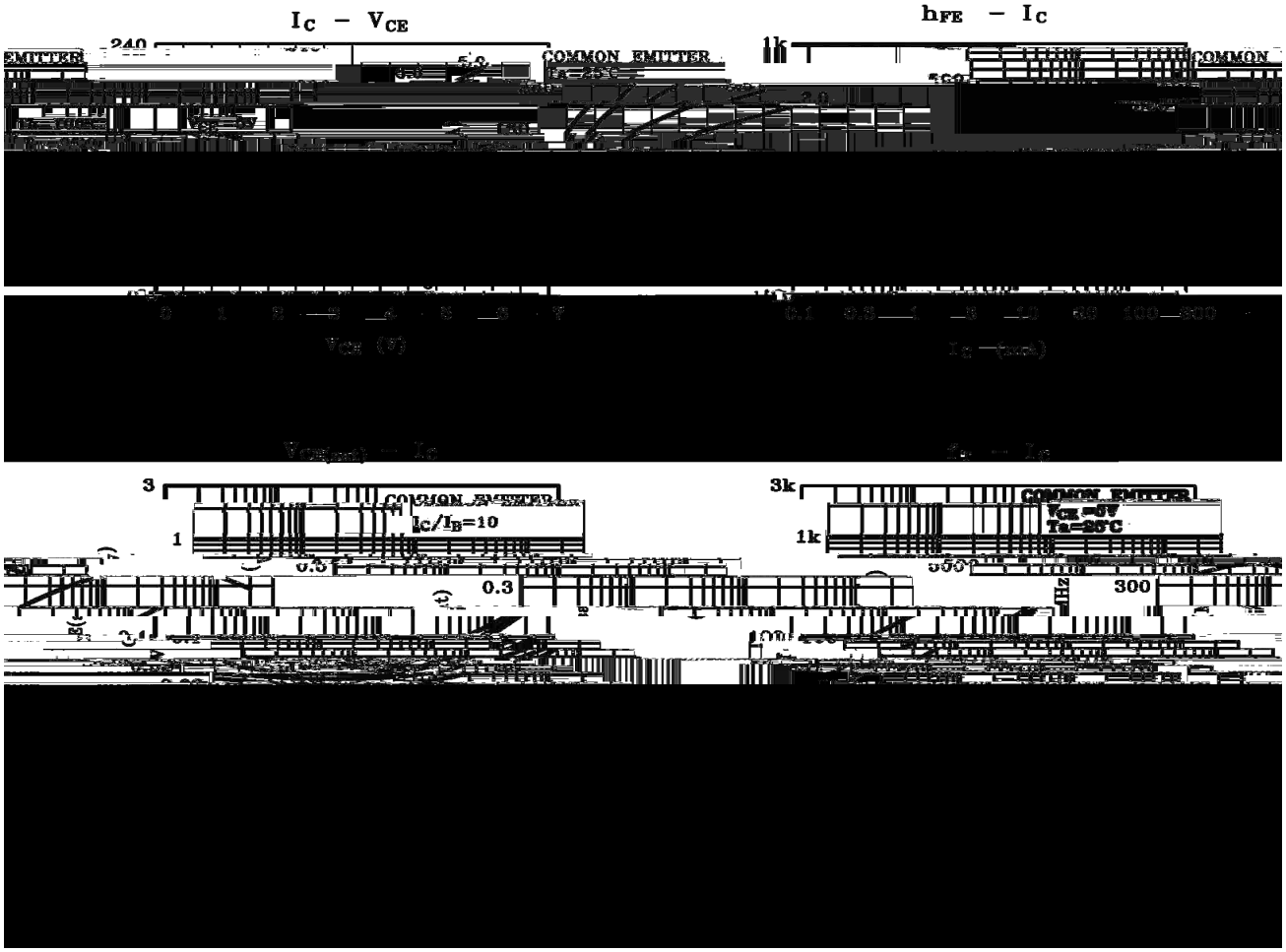


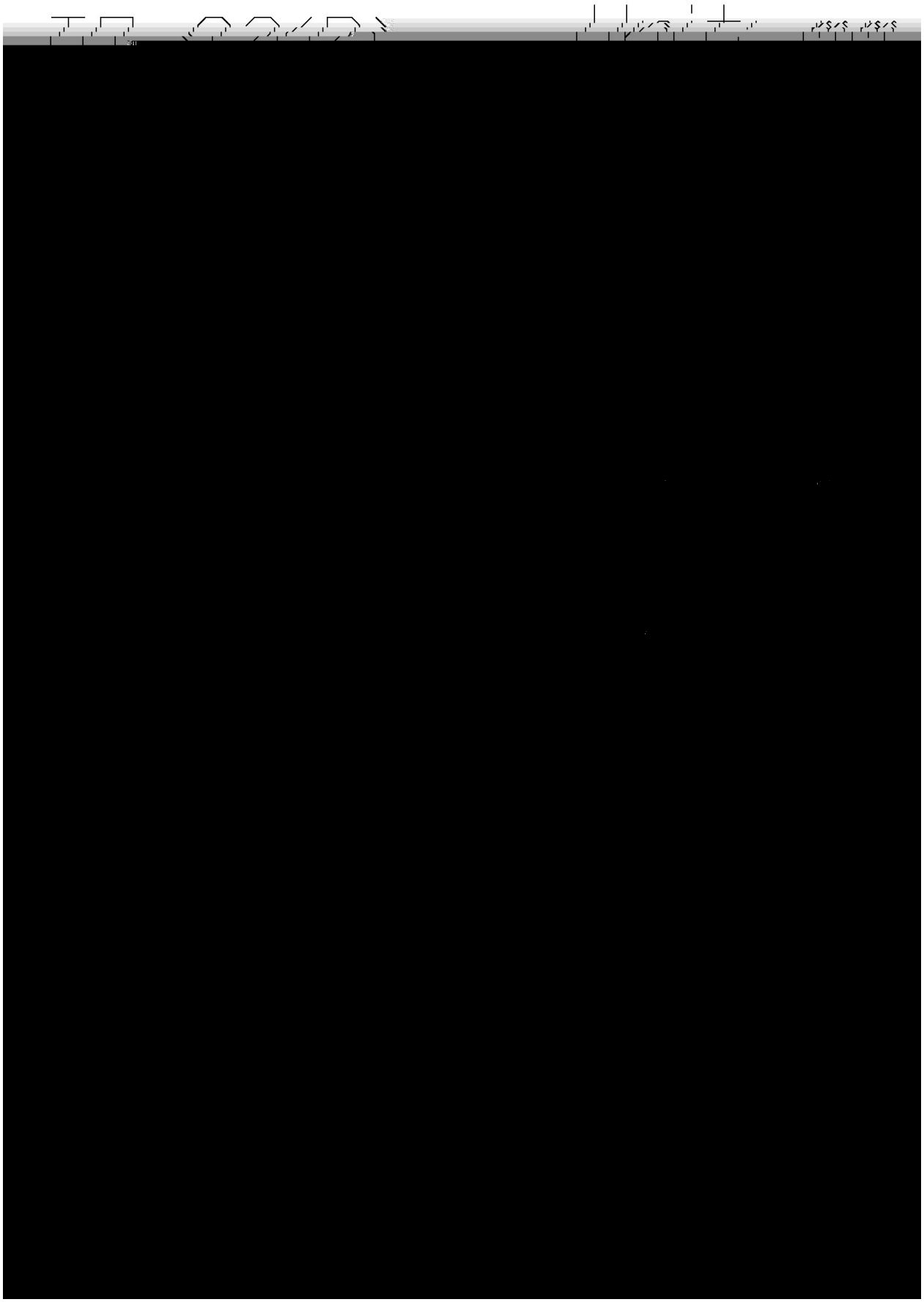


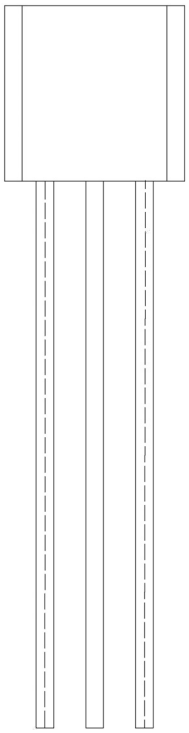
PIN1 χ Emitter PIN 2 χ Base PIN 3 χ Collector

h

h


$I_C - V_{CE}$
COMMON EMITTER
240
$h_{FE} - I_C$
1k
COMMON
3
COMMON EMITTER
$I_C/I_B=10$
1
0.3
3k
COMMON EMITTER
V_{CE}=5V
Ta=25°C
1k
300

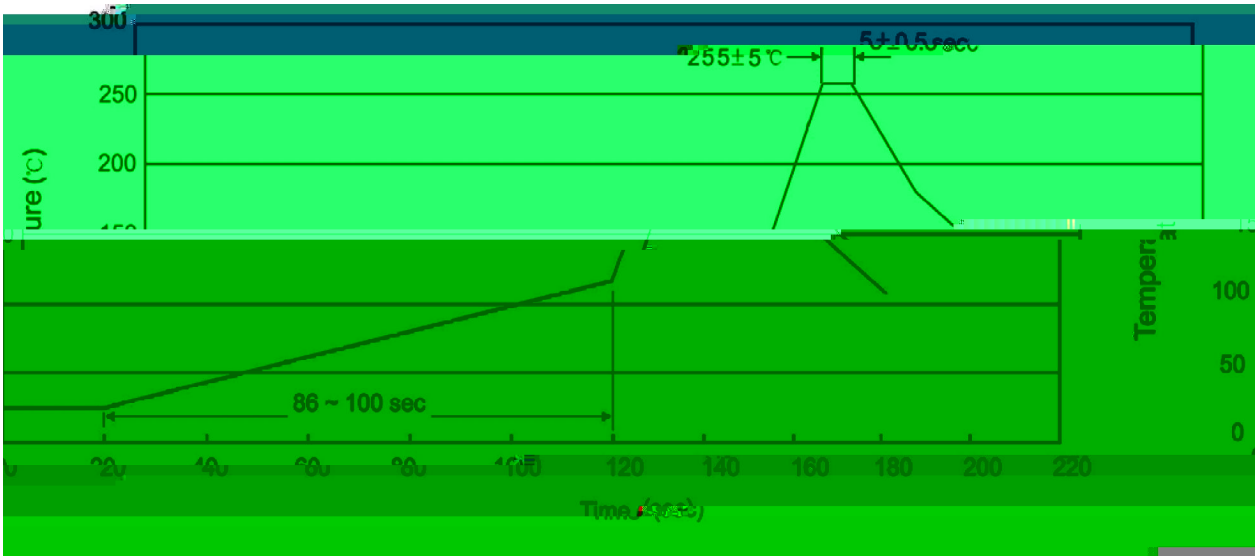




ب ˝ χ

EU χ ₶ ₹ ᴎ Ꮁ

EF879 χ ₶ ₣ β ψ ˈ ᗞ ʎ ₰ E χ Ц ض Ꮁ = ᵘ ᵘ ᵘ ᵘ χ ₶ ₣ ˈ



ب ˝ χ

1 Ĺ ♬ □ ỷ 25 Ḱ 150 ł ı ˋH ڑ 60 Ḱ 90sec;

2 Š Ö □ ỷ 255 ° 5 ł ı ˋH ڑ ˋY ﾉ ㎞ 5 ° 0.5sec;

3 ì ˙ ﾘ ˛ ↄ ﻩ ỷ ㎞ 2 Ḱ 10 ł /sec.

Note:

1.Preheating:25~150 ł , Time:60~90sec.

2.Peak Temp.:255 ° 5 ł , Duration:5 ° 0.5sec.

3. Cooling Speed: 2~10 ł /sec.

□ ỷ χ 270 ° 5 ł ˋH ڑ χ 10 ° 1 sec. Temp.:270±5 Time:10±1 sec

ˈQ ţ ﾟ Ł / BULK

Package Type	Units					Dimension		(unit mm3)
	Units/Bag /	Bags/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Bag	Inner Box	Outer Box
TO-92	1,000	10	10,000	5	50,000	135×190	237×172×102	560×245×195
	1,000	10	10,000	10	100,000	135×190	237×172×102	560×245×375

ﾉ V ﾟ Ł / AMMO

Package Type	Units					Dimension	(unit mm3)
	Units/tape /	Tape/Inner Box /	Rows/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Inner Box	Outer Box
TO-92	3,000	1	120	10	30,000	328×230×42	480×346×235 547×407×268